

EEPROM Datasheet E2PROM V 0.40

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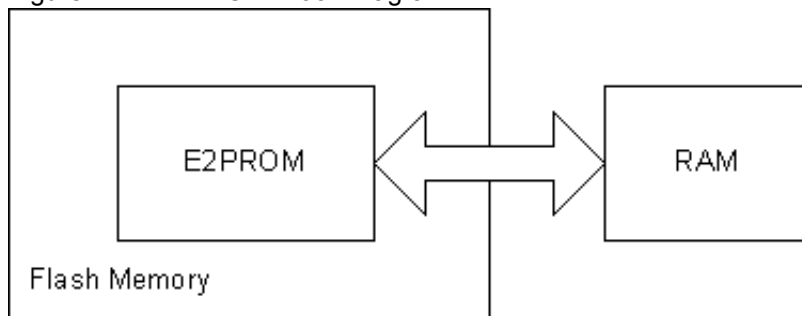
Resources	PSoC [®] Blocks			API Memory (Bytes)		Pins (per External I/O)
	Digital	Analog CT	Analog SC	Flash	RAM	
CY7C633/638/639/601/602xx, CYRF69xx3	0	0	0	727 Bytes + Size	See Below	0

Features and Overview

- Full byte-oriented EEPROM emulation
- Abstracts block-oriented flash architecture
- Efficient use of memory

The EEPROM User Module emulates an EEPROM device within the flash memory of the PSoC device. The EEPROM device can be defined to start at any flash block boundary, with a byte length from 1 to the remainder of flash memory space. The API enables the user to read and write 1 to N bytes at a time.

Figure 1. EEPROM Block Diagram



Functional Description

The EEPROM User Module is a software algorithm that uses no hardware resources of the PSoC device. One or more instances of these EEPROM virtual devices can be created.

The flash is organized for each device as 512 blocks of 64 bytes for a 32K device, 256 blocks of 64 bytes for a 16K device, 128 blocks of 64 bytes for an 8K device, and 64 blocks of 64 bytes for a 4K device. The architecture of the PSoC allows the flash data to be read on a byte-by-byte basis but requires the data to be written on a block-by-block basis – 64 bytes at a time. This user module intends to emulate an EEPROM device (a byte-read, byte-write oriented device) on a flash-based memory device (a byte-read, block-write oriented device).

The EEPROM storage area starts on a flash memory block boundary and consists of 1 or more bytes. This virtual device is accessed by using the E2Read() and E2Write() API routines. The virtual address space is from 0 to N-1, where N is the length/size in bytes of the EEPROM device.

The E2Read() API algorithm efficiently reads the flash memory byte-by-byte using the ROMX M8C instruction. This algorithm requires use of the last 8 bytes of RAM: 0xF8 to 0xFF.

The E2Write() API algorithm writes data to the flash memory on a block-by-block basis. Based on the starting address offset into the EEPROM memory space, the E2Write() routine parses the data to be written into segments that are aligned on block boundaries. This algorithm also requires use of the last 8 bytes of RAM: 0xF8 to 0xFF.

For segments that span an entire block, 64 bytes, the FlashBlockWrite() routine is called and the block is written.

For segments that are less than the 64 bytes, a temporary 64-byte stack buffer is composed of both the unwritten and modified data. After the data is written, the buffer is released from the stack. This is required to preserve the data within the block.

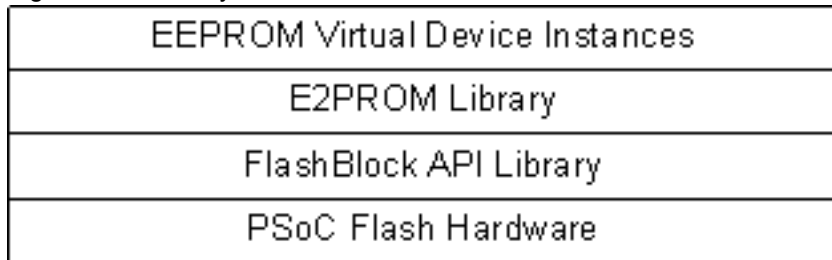
Flash read write access can only be done at a CPU clock of 12 MHz.

To reduce system overhead by optimizing parameters, see the *Parameters and Resources* section ahead.

Software Organization

The following figure shows how the software is organized into several layers consisting of two libraries and N EEPROM virtual device instances.

Figure 2. Library Structure



The FlashBlock API Library provides APIs that enable basic flash block read and write routines. These routines interface directly with the hardware and cause the device to enter System Supervisor mode. All interrupts are masked during this period. This library is only linked once, for all instances of the EEPROM virtual devices instantiated.

The E2PROM Library translates block operations into byte-wise operations by way of block alignment and buffering. It then calls the FlashBlock API Library functions to write to the flash. This library is only linked once, regardless of the number of EEPROM virtual devices.

The EEPROM virtual device layer provides a simple means to allow multiple instances of an EEPROM device, while only incurring the overhead of a single instance of both the E2PROM Library and the FlashBlock API Library. Each instance of the EEPROM virtual device contains a customized copy of this source code, which is minimal at only 16 bytes.

Both the E2PROM and the FlashBlock API libraries are included in a library file. This file automatically links into the project if calls are made to these functions.

Note These libraries are not re-entrant.

Flash Write Cycle Longevity

The flash memory has a limit with respect to the total number of lifetime writes. This device-specific total number can be found in the applicable device family datasheet.

Flash Protection

The *flashsecurity.txt* file must be edited to allow flash writes to the blocks that comprise the EEPROM device.

There is one ASCII character in *flashsecurity.txt* for each flash block of the device. The valid options for this ASCII character are 'W', 'R', 'U', and 'F'. The ASCII characters in this file define the flash security settings that are applied to each flash block. A 'W' fully protects the flash block from any writes and is the default setting. To allow the E2PROM User Module to read and write blocks the protection option should be changed to 'R', 'F', or 'U'. The option should be changed for each flash block that is occupied by the E2PROM. To properly change the security settings in *flashsecurity.txt*, delete the character corresponding to the flash block to be affected. Type in a new character corresponding with the desired security setting. Save the project and rebuild it to ensure that the changed settings have taken effect.

Mode	Settings	Description	In PSoC Designer
00b	SR ER EW IW	Unprotected	U = Unprotected
01b	SR ER EW IW	Read protect	F = Factory upgrade
10b	SR ER EW IW	Disable external write	R = Field upgrade
11b	SR ER EW IW	Disable internal write	W = Full protection

Efficient Memory Use

Use the following guidelines to maximize the efficiency of both RAM and flash resources.

If Flash Memory is Plentiful (Efficient use of RAM)

- Create EEPROM devices in multiples of 64-byte lengths, even if the data to be stored is less.
- Always write the data in multiples of 64-byte lengths.
- Always read the data with the correct byte count.

For example, if the serial number data is 10 bytes in length, create an EEPROM User Module with the name serial number. Set the Length parameter to 64. This allocates a 64-byte block in flash memory. In RAM, set up a 10-byte data array to hold the serial number data. When writing the serial number using `E2Write()`, specify the `wByteCount` parameter as 64. However, when reading the serial number data, specify the `wByteCount` parameter as 10.

If Flash Memory is at a Premium (Efficient use of Flash)

- Create EEPROM devices using only the required number of bytes.
- Always write the data with the correct byte count.
- Always read the data with the correct byte count.

DC and AC Electrical Characteristics

See the device datasheet for your enCoRe device for electrical characteristics of the flash.

Timing

The timing of the EEPROM algorithms is summarized in the following table:

Unless otherwise specified in the following table, all limits guaranteed for $T_A = 25\text{ }^\circ\text{C}$, $V_{dd} = 5.0\text{ V}$.

Table 1. EEPROM Timing

Parameter	Conditions and Notes	Typical	Limit	Units
Time to Write 0°C-100°C	Time to write depends on the number of flash blocks that require an update. ^{1,2}	45	120 ^{3,4}	mS/Block
Time to Write -40°C-0°C	Time to write depends on the number of flash blocks that require an update. ^{1,2}	70	240 ^{3,4}	mS/Block
Time to Read	81 + 46N Clock Cycles	--	--	Clks/Bytes
	Worst Case is 1 Byte:	--	127	
	For 16 Bytes: $(81+46(16))/10$	51	--	
	For 64 Bytes: $(81+46(64))/64$	48	--	

Timing Notes

1. Interrupts are masked during flash read and write operations during the time the M8C is in the System Supervisor mode.
2. Time to write is determined by the FlashBlockWrite() routine to erase and write each flash block.
3. Total number of flash writes is limited. See the part-specific datasheet for specifications on number of write cycles per block.
4. Limit is specified for normal programmed operation. In emulation mode using the debugger, the write pulse may be up to 200 mS in width.

Placement

The EEPROM User Module is implemented in software and does not require placement.

Parameters and Resources

FirstBlock

The FirstBlock is the starting block in which the EEPROM device resides. Values range from 0 to the maximum number of flash blocks for the specific device: 511 for 32K devices, 255 for 16K devices, 127 for 8K devices, 63 for 4K devices, and 31 for 2K devices.

Special care must be taken to ensure that the E2PROM user module's flash memory location does not overlap any code or other important data located in the flash. You should place the E2PROM memory location as high as possible in the flash memory. For instance, if the device has 512 blocks of flash, locating the E2PROM user module at flash block 511 would be a good choice. Locating it at flash block 0 would likely cause system failure, since the E2PROM location would overlap the interrupt vectors. Any write operation to an E2PROM at block 0 would overwrite the interrupt vector table. Locating the E2PROM near the middle of the flash memory is also not a good practice. The Image-Craft compiler's linker cannot split up your code into separate memory areas. Therefore, as your code gets larger, it eventually overlaps the E2PROM location near the middle of the flash memory.

Length

The length defines the size, in bytes, of the EEPROM device. The valid range is from 1 to N, where N is the size of EEPROM virtual device in bytes.

Warning Ensure that the physical location of the virtual EEPROM device does not exceed the flash size of the device. The first physical byte of the EEPROM device is located at $\text{FirstBlock} * 64$. The last byte of the virtual device is physically located at $\text{FirstBlock} * 64 + \text{Length} - 1$. Error checking is not performed. Failure to ensure that the size is not exceeded may result in unpredictable flash writes to unintended blocks.

RAM Memory Overhead

The following RAM memory resources are used:

Table 2. RAM Memory Resources

API Routine	Memory Utilization
E2Read()	Stack Space: 8 Bytes RAM High Memory: 0xF8 – 0xFF
E2Write() with NO Partial Block Writes	Stack Space: 32 Bytes RAM High Memory: 9 Bytes 0xF8 – 0xFF
E2Write() with Partial Block Writes	Stack Space: 103 Bytes RAM High Memory: 9 Bytes 0xF8 – 0xFF

Application Programming Interface

The Application Programming Interface (API) routines are provided as part of the user module to allow the designer to deal with the module at a higher level. This section specifies the interface to each function together with related constants provided by the "include" files.

Note

In this, as in all user module APIs, the values of the A and X registers may be altered by calling an API function. It is the responsibility of the calling function to preserve the values of A and X before the call if those values are required after the call. This "registers are volatile" policy was selected for efficiency reasons and has been in force since version 1.0 of PSoC Designer. The C compiler automatically takes care of this requirement. Assembly language programmers must ensure their code observes the policy, too. Though some user module API functions may leave A and X unchanged, there is no guarantee they may do so in the future.

For Large Memory Model devices, it is also the caller's responsibility to preserve any value in the CUR_PP, IDX_PP, MVR_PP, and MVW_PP registers. Even though some of these registers may not be modified now, there is no guarantee that will remain the case in future releases.

The EEPROM User Module APIs are described as follows.

E2PROM_Start

Description:

A null function, maintained for user module API consistency.

C Prototype:

```
void E2PROM_Start(void)
```

Assembler:

```
lcall E2PROM_Start
```

Parameters:

None

Return Value:

None

Side Effects:

The A and X registers may be modified by this or future implementations of this function.

E2PROM_Stop

Description:

A null function, maintained for user module API consistency.

C Prototype:

```
void E2PROM_Stop(void)
```

Assembler:

```
lcall E2PROM_Stop
```

Parameters:

None

Return Value:

None

Side Effects:

The A and X registers may be modified by this or future implementations of this function.

E2PROM_bE2Write**Description:**

Writes the specified data to the defined EEPROM from a RAM buffer. Note that the *flashsecurity.txt* file must be set properly to allow writing to flash.

C Prototype:

```
CHAR E2PROM_bE2Write(WORD wAddr, BYTE *pbData, WORD wByteCount,  
                    CHAR cTemperature);
```

Assembly:

```
push X  
mov X, SP  
mov A, <cTemperature> ; cTemperature argument  
push A  
mov A, <wByteCount> ; wByteCount - MSB  
push A  
mov A, <wByteCount+1> ; wByteCount - LSB  
push A  
mov A, <pbData> ; pbData - MSB  
push A  
mov A, <pbData+1> ; pbData - LSB  
push A  
mov A, <wAddr> ; wAddr - MSB  
push A  
mov A, <wAddr+1> ; wAddr - LSB  
push A  
lcall E2PROM_bE2Write  
add SP, -E2_WR_ARG_STACK_FRAME_SIZE ; restore call stack  
pop X
```

Where <..> refers to any addressing mode or number of instructions to place referenced data into the Accumulator.

Parameters:

wAddr: Address offset of the EEPROM device address space from which the RAM data is written. It can be 0 to the N-1, where N is the length of the EEPROM device. pbData: Pointer to the RAM buffer that contains data to write. wByteCounter: Number of bytes to write to flash. cTemperature: Temperature of the PSoC die, in degrees Celsius. This value can be specified by using one of the following:

- A user module, such as FlashTemp.
- An external device or sensor.
- A nominal value that applies to all environmental conditions that the PSoC device experiences. For example, room temperature = 25°C.

Return Values:

The following values can be returned:

Return Flag	Description	Value
NOERROR	Successful completion of operation.	0
FAILURE	Unsuccessful completion of operation. Most likely a result of flash-protection bit errors.	-1
STACKOVERFLOW	Stack space was not sufficient for algorithm requirements.	-2

Side Effects:

The A and X registers may be modified by this or future implementations of this function.

E2PROM_E2Read

Description:

Reads the specified EEPROM device data from flash into the specified RAM buffer.

C Prototype:

```
void E2PROM_E2Read(WORD wAddr, BYTE *pbData, WORD wByteCount)
```

Assembler:

```
push X
mov X, SP
mov A, <wByteCount> ; wByteCount - MSB
push A
mov A, <wByteCount+1> ; wByteCount - LSB
push A
mov A, <pbDataDest> ; pbDataDest - MSB
push A
mov A, <pbDataDest+1> ; pbDataDest - LSB
push A
mov A, <wAddr> ; wAddr - MSB
push A
mov A, <wAddr+1> ; wAddr - LSB
push A
lcall E2PROM_E2Read
add SP, -E2_RD_ARG_STACK_FRAME_SIZE ; restore call stack
pop X
```

Where <..> refers to any addressing mode or number of instructions to place referenced data into the Accumulator.

Parameters:

wAddr: Address offset of the EEPROM device address space from which the flash data is read. It can be 0 to the N-1, where N is the length of the EEPROM device. pbData: Pointer to the RAM buffer that data is read into. wByteCounter: Number of bytes to read from flash.

Return Value:

None

Side Effects:

The A and X registers may be modified by this or future implementations of this function.

Sample Firmware Source Code

The following is C language source code.

```

/*****
/**  EEPROM User Module Example Code:
/**
/**  A SerialNumber EEPROM was created to start at block 250 with a length
/**  of 10 bytes. Remember to edit the Flashsecurity.txt file to allow
/**  writes to flash (Set the 250th block to U - Unprotected).
/**
/**  This example:
/**
/**      a) Writes the initial data to the EEPROM block area
/** Note that this will invoke the SavePartial algorithm which
/** allocates a temporary 64-byte buffer on the stack. If
/** Flash memory is plentiful and the extra 54 bytes can be
/** wasted, set the SerialNumber device to a length of 64 and when
/** writing, specify a bytecount of 64. This will write an entire
/** block without using a temporary buffer. The extra 54 bytes
/** beyond the SerialNumber will be bogus data.
/**
/**      b) Reads the data back into a RAM buffer
/**
/*****/

#include <m8c.h>          // part specific constants and macros
#include "PSoCAPI.h"     // PSoC API definitions for all User Modules

#define ADDRESS_OFFSET    0
#define NUMBER_OF_BYTES  10
#define TEMPERATURE       25

/* Initialize a RAM buffer with default Serial Number */
BYTE  abInitialSerialNumber[] = {'0','1','2','3','4','5','6','7','8','9' };
BYTE  abSerialNumberBuffer[NUMBER_OF_BYTES];

void main(void)
{
    BYTE bError;

    /* Write the Serial Number - assume temp of 25C */
    bError = E2PROM_bE2Write(ADDRESS_OFFSET, abInitialSerialNumber, NUMBER_OF_BYTES,
    TEMPERATURE);

    if ( bError == E2PROM_NOERROR )
    {
        /* Read the Serial Number back into a RAM buffer */
        E2PROM_E2Read( ADDRESS_OFFSET, abSerialNumberBuffer, NUMBER_OF_BYTES );
    }

    while(1)
    {
    }
}

```

}

The same code in assembly is:

```

;*****
;   EEPROM User Module Example Code:
;
;   A SerialNumber EEPROM was created to start at block 250 with a length
;   of 10 bytes. Remember to edit the Flashsecurity.txt file to allow
;   writes to Flash (Set the 250th block to U - Unprotected).
;
;   This example:
;
;   a) Writes the initial data to the EEPROM block area
;   Note that this will invoke the SavePartial algorithm which
;   allocates a temporary 64-byte buffer on the stack. If
;   Flash memory is plentiful and the extra 54 bytes can be
;   wasted, set the SerialNumber device to a length of 64 and when
;   writing, specify a bytecount of 64. This will write an entire
;   block without using a temporary buffer. The extra 54 bytes
;   beyond the SerialNumber will be bogus data.
;
;   b) Reads the data back into a RAM buffer
;
;*****
include "m8c.inc"      ; part specific constants and macros
include "memory.inc"  ; Constants and macros for SMM/LMM and Compiler
include "PSoCAPI.inc" ; PSoc API definitions for all User Modules

ADDRESS_OFFSET:      equ      0
NUMBER_OF_BYTES:     equ      10
TEMPERATURE:         equ      25

export _main

export  abSerialNumberString
export  abInitialSerialNumber
export  abSerialNumberBuffer
export  bCounter
export  pPtr

        AREA    bss      (RAM,REL)

abInitialSerialNumber:  blk    NUMBER_OF_BYTES    ; string holds initial serial data
abSerialNumberBuffer:  blk    NUMBER_OF_BYTES    ; buffer to read back serial data
bCounter:              blk    1                  ; counter to load initial string
pPtr:                  blk    1                  ; pointer to initial string

        AREA    text    (ROM,REL)

;Table to hold initial serial number string
.LITERAL
abSerialNumberString:  db      '0','1','2','3','4','5','6','7','8','9'
.ENDLITERAL

```

```

_main:

; load the serialnumber into RAM
  mov    [bCounter], NUMBER_OF_BYTES          ; load 10 bytes from ROM into RAM

RAM_SETPAGE_MVR >abInitialSerialNumber
RAM_SETPAGE_MVW >abInitialSerialNumber
  mov    [pPtr], <abInitialSerialNumber ; ptr RAM data to put Flash data
  mov    X, <abSerialNumberString      ; LSB of abSerialNumberString
  mov    A, >abSerialNumberString      ; MSB of abSerialNumberString

; Use ROMX and MVI to copy the data from Flash to RAM
.loop:
  push   A                                  ; Save MSB of abSerialNumberString to Stack
  romx
  mvi    [pPtr], A                          ; Save the value to RAM
  pop    A                                  ; Get MSB of abSerialNumberString from Stack
  inc    X                                  ; Increment LSB of abSerialNumberString
  dec    [bCounter]
  jnz    .loop

; Write the Serial Number - assume temp of 25C
  mov    A, TEMPERATURE                     ; temperature = 25C
  push   A
  mov    A, >NUMBER_OF_BYTES                ; MSB of wByteCount = 0
  push   A
  mov    A, <NUMBER_OF_BYTES                ; LSB of wByteCount = 10
  push   A
  mov    A, >abInitialSerialNumber          ; MSB of pbDest= >abInitialSerialNumber
  push   A
  mov    A, <abInitialSerialNumber          ; LSB of pbDest=abInitialSerialNumber
  push   A
  mov    A, >ADDRESS_OFFSET                 ; MSB of wAddr=0
  push   A
  mov    A, <ADDRESS_OFFSET                 ; LSB of wAddr=0
  push   A
  call   E2PROM_be2Write                    ; Write the data
  add    SP, -E2_WR_ARG_STACK_FRAME_SIZE
  pop    X

;if ( bError == NOERROR )
  cmp    A, 0
  jnz    .ExampleDone

; Read the Serial Number back into a RAM buffer
  mov    A, >NUMBER_OF_BYTES                ; MSB of wByteCount = 0
  push   A
  mov    A, <NUMBER_OF_BYTES                ; LSB of wByteCount = 10
  push   A
  mov    A, >abSerialNumberBuffer           ;MSB of pbDest= >abSerialNumberBuffer
  push   A

```

```

mov     A, <abSerialNumberBuffer      ; LSB of pbDest=abInitialSerialNumber
push   A
mov     A, >ADDRESS_OFFSET            ; MSB of wAddr=0
push   A
mov     A, <ADDRESS_OFFSET            ; LSB of wAddr=0
push   A
call   E2PROM_E2Read
add    SP, -E2_RD_ARG_STACK_FRAME_SIZE
pop    X

```

```

.ExampleDone:
    jmp .ExampleDone

```

Version History

Version	Originator	Description
0.2	DHA	Added Version History
0.30	DHA	1. Updated the sample code in this user module datasheet. 2. Updated max value of FirstBlock.
0.40	DHA	1. Added support for 4K flash devices CY7C63801-PXC and CY7C63801-SXC. 2. Updated assembler sample firmware source code.
0.40.b	DHA	Added explanation about SysClk and Flash read and write access in the user module datasheet.

Note PSoC Designer 5.1 introduces a Version History in all user module datasheets. This section documents high level descriptions of the differences between the current and previous user module versions.

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